

## PROGRAM

Sunday, April 29, 17:00-21:00- **Registration, welcome tea (Faculté des Sciences et Techniques Gueliz Marrakech)**

Monday, April 30			Tuesday, May 1			Wednesday, May 2			
<b>( 8:30-9:30)- Opening</b> <b>Plenary A-1</b> 9:30-10:00 - 10:00-10:30 - Room A(Amphi I)			<b>Plenary A-2</b> Room A(Amphi I)			<b>Plenary A-3</b> Room A(Amphi I)			
10:30 –10:50 Coffee Break			Coffee Break			Coffee Break			
10:50-11:10 -	<b>1C-1</b>	<b>2C-1</b>	<b>3C-1</b>	<b>1C-2</b>	<b>2C-3</b>	<b>4C-2</b>	<b>4C-4</b>	<b>2C-4</b>	<b>3C-4</b>
11:10-11:30 -	Room A	Room B	Room C	Room A	Room B	Room C	Room A	Room B	Room C
11:30-11:50 -	(Amphi I)	(Amphi II)	(Salle 22)						
11:50-12:10 -									
12:10 – 14:30 Lunch			Lunch			Lunch			
14:30-14:50 -	<b>4C-1</b>	<b>2C-2</b>	<b>3C-2</b>	<b>1C-3</b>	<b>4C-3</b>	<b>3C-3</b>	<b>1C-4</b>	<b>4C-5</b>	<b>3C-5</b>
14:50-15:10 -	Room A	Room B	Room C	Room A	Room B	Room C	Room A	Room B	Room C
15:10-15:30 -									
15:30-15:50 -									
15:50 –16:10 Coffee Break			Coffee Break			Coffee Break			
16:10-16:30 -	<b>Plenary B-1</b>		<b>Plenary B-2</b>			<b>Plenary B-3</b>			
16:30-16:50 -	Room A		Room A			Room A			
16:50-17:10 -									
17:10- ...	<b>Poster Presentation D-1</b>		<b>Poster Presentation D-2</b>	<b>Round Table</b>		<b>Poster Presentation D-3</b>			
	2-3 min. for presentation		2-3 min. for presentation			2-3 min. for presentation			
... - 19:15	<b>Posters</b>		<b>Posters</b> (Semiconductors, nanomaterials...)			<b>Posters</b> (Multifunctional materials)			
	(Dielectrics, magnetics...)								
			19:00 Gala Dinner			18:45-19:00 - Closing			

### Sessions:

**1C-x** Dielectric materials, magnetic Materials

**2C-x** Semiconductors, Sensors

**3C-x** Nano materials

**4C-x** Materials Telecommunication, Energy and Natural materials

## Monday, April 30

**Plenary A-1, Room A, Chair: A. Bratkovski**

8:30 -9:30	- Opening		
9:30-10:00 10:00-10:30	<p><i>J. F. SCOTT Analyzing Dielectric Materials for Electronic Applications</i></p> <p><i>I. SAADOUNE Positive Electrode Materials For High Energy</i></p>		
<b>10:30 –10:50</b>	<b>Coffee Break</b>		
10:50-11:10 11:10-11:30 11:30-11:50 11:50-12:10	<p style="text-align: center;"><b>1C-1 Room A, Chair: M. Elmarsi</b></p> <p><u>Bormanis K.</u> <i>Low-frequency dielectric response of disordered perovskite ceramics</i></p> <p><u>LIMAM K.</u> <i>Properties of sol gel processed Pb1-xLaxTiO3 samples</i></p> <p><u>Mercone S.</u> <i>Low Frequency Noise In La2/3sr1/3mno3 Devices</i></p> <p><u>Echatoui N.-S.</u> <i>Etude numerique du nonstante dielectrique dans les céramiques PLZT et BZT</i></p>	<p style="text-align: center;"><b>2C-1 Room B, Chair: A. Kadri</b></p> <p><u>L. Essaleh</u> <i>MAGNETOTRANSPORT IN DOPED SEMICONDUCTORS APPLICATION TO COPPER TERNARIES</i></p> <p><u>N Fazouan.</u> <i>A Monte Carlo growth and characterization of heteroepitaxial thin films</i></p> <p><u>Ramdane M.</u> <i>Properties of multi-layer semiconductor thin films</i></p> <p><u>Rouabah Z.</u> <i>Electron mobility in silicon for the energy range 0.5-4 kev</i></p>	<p style="text-align: center;"><b>3C-1 Room C, Chair: A. El hidy</b></p> <p><u>Bouzabata B.</u> <i>Structural and magnetic behaviour of nanostructured fex(x=ni,si,al) alloys</i></p> <p><u>Raevskaya S.</u> <i>Dielectric studies of NaNbO3 –based lead-free relaxor ceramics and lead-containing relaxors</i></p> <p><u>Bouklouch M.</u> <i>Modelisation Des Proprietes Electriques d'un Milieu Granulaire Sous Une Tension</i></p> <p><u>Habouti S.</u> <i>Sol-Gel-Derived Multiferroic BiFeO3 Thin Films. an Overview on Microstructure and Properties</i></p>
<b>12:10 –14:30</b>	<b>Lunch</b>		
14:30-14:50 14:50-15:10 15:10-15:30 15:30-15:50	<p style="text-align: center;"><b>4C-1 Room A, Chair: Miane J.L.</b></p> <p><u>Kaddami H.</u> <i>Valorisation du palmier dattier dans le domaine des matériaux nanocomposites</i></p> <p><u>Charef T.</u> <i>Evolution Structurale en Fonction de T d'un Composé Inorganique Optiquement non Lineaire</i></p> <p><u>M Bour.</u> <i>Analysis of coaxial/cylindrical cell for the characterization of magnetic anisotropic materials.</i></p> <p><u>Quispe S.</u> <i>Pulsed photoacoustic for the study of linbo3:Nd3+,Mg2+ single crystal</i></p>	<p style="text-align: center;"><b>2C-2 Room B, Chair: I. Raveaski</b></p> <p><u>A El Mahdi.</u> <i>Exact analytical solutions of graëtz bridge</i></p> <p><u>B Benichou.</u> <i>3d Modelling Of Relaxation Semiconductor Structure. GaAs P-N Deep Trap Centres.</i></p> <p><u>K Amechnou.</u> <i>The simulation of the transport phenomena in semiconductors</i></p> <p><u>Ramdan M.</u> <i>Study of the SiNx materials properties heavily implanted boron</i></p>	<p style="text-align: center;"><b>3C-2 Room C, Chair: M. Al aatmani</b></p> <p><u>Kalboussi A.</u> <i>Noise analysis and dlts investigations in si-nanocrystal-based mos structures</i></p> <p><u>EI Marssi M.</u> <i>Stress, orientation and phase transitions in the ferroelectric superlattices</i></p> <p><u>Nour E Hakiki.</u> <i>Structural and semiconducting properties of thin passive films formed on stainless steels</i></p> <p><u>A Gorshkov.</u> <i>Crystallization of thin-film amorphous nanocomposites COx(PZT)1-x</i></p>
<b>15:50 –16:10</b>	<b>Coffee Break</b>		
16:10-16:30 16:30-16:50 16:50-17:10	<p style="text-align: center;"><b>Plenary B-1, Room A, Chair: J. F. Scott</b></p> <p><i>A. ROUGIER Electrochromic Materials Active In The Ir Region</i></p> <p><i>EI Haskouri J.I Nouvelles nanoparticules uniformes dans le monde de la nanotechnologie</i></p> <p><i>Morrison F. D. Modelling of ferroelectric random-access memory PZT capacitors</i></p>		
<b>17:10- ...</b>	<p style="text-align: center;"><b>Poster Presentation D-1 (2-3 min. for presentation ), Room A Chair: J. L. Dellis</b></p> <p style="text-align: center;">Presentations: 1D027, 1D030, 1D032, 1D033, 1D034, 1D035, 1D037, 1D038, 1D039, 1D040, 1D041</p>		
<b>...- 19:15</b>	<p style="text-align: center;"><b>Posters (Ferroelectrics, Ferromagnetics...) 1Dxxx, 1Pxxx,</b></p>		

**Tuesday, May 1**

**Plenary A-2, Room A, Chair: B. Elouadi**

9:00-9:30 *J.-L. MIANE New Structures And Materials In Telecommunications*  
 9:30-10:00 *A. BRATKOVSKI Spintronics And Plasmonics For Nanoelectronics In 21st Century*  
 10:00-10:30 *M. ELLOUZE Study Of The Crystallographic And Magnetic Properties Of Lacunar Perovskites Containing Praseodymium*

**10:30 –10:50** Coffee Break

	<b>1C-2 Room A, Chair: S. Sayouri</b>	<b>2C-3 Room B, Chair: I. Stevenson</b>	<b>4C-2 Room C, Chair: M. Ellouze</b>
10:50-11:10	<u>Achour S.</u> <i>Modélisation et prédiction de comportement diélectrique de matériaux</i>	<u>C Boulanger.</u> <i>Influence of electroplating conditions on semiconductor and thermoelectric BiTe films</i>	<u>Benslama M.</u> <i>Shear horizontal bulk waves of langasite-type for oscillators in space communications devices</i>
11:10-11:30	<u>Baudry L.</u> <i>Polarization switching kinetic in ferroelectric films</i>	<u>K. Akmoum</u> <i>CINETIQUE D'AMORPHISATION DU GaAs PAR IMPLANTATION IONIQUE DE XENON</i>	<u>Amara A.</u> <i>Electrical and optical characterization of cuins2 crystals and polycrystalline coevaporated thin films</i>
11:30-11:50	<u>El Amraoui Y.</u> <i>An amorphous Ising thin film: Monte Carlo simulations.</i>	<u>S Berrah.</u> <i>Optical properties of ingan</i>	<u>L El Maimouni.</u> <i>Acoustical guided waves in inhomogeneous cylindrical materials</i>
11:50-12:10	<u>E.-S. El-Frikhe.</u> <i>Theoretical studies on the ferroelectric properties of ferroelectric thin films</i>	<u>A. BENACHENHOU</u> <i>DETERMINATION OF THERMOLUMINESCENCE KINETICS PARAMETERS OF ALUMINE (<math>\alpha</math>-AL<sub>2</sub>O<sub>3</sub>) BY THE LEAST SQUARES METHOD</i>	<u>M Azrou.</u> <i>Etude structurale et de proprietes physiques des apatites lacunaires a base du vanadium</i>

**12:10 –14:30** Lunch

	<b>1C-3 Room A, Chair: L. Bih</b>	<b>4C-3 Room B, Chair: A. Rougier</b>	<b>3C-3 Room C, Chair: Y. El Amraoui</b>
14:30-14:50	<u>A. Toumanari</u> <i>Microscopic coupling effects in ferroelectrics superlattice</i>	<u>Couraudon V.</u> <i>Characterization of organic solar cells materials and structures ...</i>	<u>B Inas.</u> <i>Structure, dielectric and ESR studies of nano-composite Fe<sub>2</sub>O<sub>3</sub>:BaTiO<sub>3</sub></i>
14:50-15:10	<u>Catalan G.</u> <i>Domain periodicity in nanoferroelectrics</i>	<u>H. Chaib.</u> <i>Dielectric Polarization and Refractive Indices of Ultrathin BaTiO<sub>3</sub> Films on SrTiO<sub>3</sub> Single Crystals.</i>	<u>B Bouguerra.</u> <i>Structural and magnetic studies of nanocrystalline fex (x=si,al,ni) alloys</i>
15:10-15:30	<u>Raevski I.</u> <i>Magnetic and ferroelectric transitions in BiFeO<sub>3</sub>-NaBO<sub>3</sub> ceramics</i>	<u>A Feddag.</u> <i>Flexibilité De La Coordination De l'aluminium Dans Les Silicates.</i>	<u>Kaynts D.</u> <i>Formation of ferroelectric nanostructures in (as<sub>2</sub>s<sub>3</sub>)<sub>100-x</sub>(sbsi)<sub>x</sub> glassy matrix</i>
15:30-15:50	<u>Zubko P.</u> <i>Flexoelectricity in strontium titanate single crystals</i>	<u>Ahmadouche A.</u> <i>Capteur Electrooptique de Champ Électrique À Base de Polymères</i>	<u>Khachane M.</u> <i>Ba<sub>2</sub>nanb<sub>5o</sub>15 films prepared by rf magnetron sputtering and their caractérisation</i>

**15:50 –16:10** Coffee Break

**Plenary B-2, Room A, Chair: M. Fontana**

16:10-16:30 Kavokin A. *Polariton lasers.*  
 16:30-16:50 Elouadi B. *Cationic disorder and its effect on niobates with TTB structure*  
 16:50-17:10 K. Abderrahmane. *Laser gain optimization in zno/mgzno quantum well nanostructures*

**17:10- ...** **Poster Presentation D-2** (2-3 min. for presentation ), Room A Chair: L. Essaleh

Presentations: 2D089, 2D090, 2D091, 2D092, 2D093, 2D094, 2D095, 2D096, 3D163, 3D164, 3D165, 3D166, 3D167, 3D168, 3D169

**Round Table:**  
"Collaboration"

**...- 19:15** **Posters** (Semiconductors, nanomaterials...) 2Dxxx, 3Dxxx, 2Pxxx, 3Pxxx,

**19:00 Gala Dinner**

**Wednesday, May 2**

**Plenary A-3, Room A, Chair: A. Kavokin**

9:00-9:30 *G. BOITEUX, I. STEVENSON, G. SEYTRE Relation Between Architecture / Organisation Of Macromolecular Chains and Dielectric Properties*  
 9:30-10:00 *A. KADRI Advanced Nanostructured Semiconductor Heterostructures For Nanotechnologies*  
 10:00-10:30 *E. RUIZ-HITZKY Polymer-Clay Nanocomposites: Advanced Materials For Electrochemical and Electroanalytical Applications*

**Coffee Break**

<b>4C-4 Room A, Chair: L. Baudry</b>	<b>2C-4 Room B, Chair: A. Chahboun</b>	<b>3C-4 Room C, Chair: J. I. El Haskouri</b>
10:50-11:10 <i><u>El Hasri S.</u> Organisation du Polystyrène amorphe induit par diffusion du solvant</i>	<i><u>Alga Maati.</u> Quelques reflexions sur les proprietes electriques des bimevox</i>	<i><u>A El Mahdi.</u> Exact analytical solutions for shallow impurity states in symmetrical quantum dots</i>
11:10-11:30 <i><u>Lethiecq M.</u> Piezoelectric materials and high frequency ultrasonic devices</i>	<i><u>A Belgacem-Bouzida.</u> L'etude Thermodynamique des (Ga-M) (M=Nb, Mo, Cr) : technologie Semi-Conducteurs</i>	<i><u>Benotmane A.</u> Théorie Moléculaire De Génération Fréquence Somme Doublement Résonnante (Dr-Sfg):</i>
11:30-11:50 <i><u>Al-Shakerji.</u> Ultra-fine powder of BaTiO3 using freeze-drying process</i>	<i><u>O Meglali.</u> Neutron irradiation effects on the electrical and optical properties of fz silicon</i>	<i><u>S Madani.</u> Numerical simulation of the stress field of an gaas/gaas anisotropic twist boudary</i>
11:50-12:10 <i><u>El J Belgacem.</u> Effect of thermal annealing on properties of thin GaAs(1-x)Bi(x) (x=0.037) alloy</i>	<i><u>M. BenYoussef</u> Effet des impuretés sur les mécanismes de recristallisation dans le cuivre</i>	<i><u>T Outtas.</u> Free surface nanopaterning with burried hexagonal dislocations array: Simulation</i>

**Lunch**

<b>1C-4 Room A, Chair: F.D. Morison</b>	<b>4C-5 Room B, Chair: K. Akmoum</b>	<b>3C-5 Room C, Chair: H. Khemakhem</b>
14:30-14:50 <i><u>Y. Gagou PKN,</u> TTB ferroelectric thin films</i>	<i><u>C L Cadillon</u> Polymer composites for preventing microwave leakage in heating ovens</i>	<i><u>F Z El Berrichi.</u> Synthèse Du Matériau Composite SBA-15 Supporté Sur Du Carbure De Si : <math>\beta</math>(?-Sic)</i>
14:50-15:10 <i><u>Raihane M</u> Molecular dynamics of a fluorinated cyano copolymer</i>	<i><u>K Kassmi</u> Modélisation des propriétés de conduction des diodes schottky en polymère</i>	<i><u>K. Zitouni</u> Optical Gain &amp; Laser threshold engineering in InGaAsSb/AlGaAsSb Mid-Infrared Quantum Well Laser Nanostructures</i>
15:10-15:30 <i><u>A Koumina,</u> Properties of the transition metal pnictides MM'X (x = P, As)</i>	<i><u>Latifa S.</u> Caracterisation ...de Gisements d'argiles de la Region De Marrakech</i>	<i><u>Rhouta B.</u> Electrical and electrokinetic studies of al-pillared moroccan clay</i>
15:30-15:50	<i><u>M Chouiti.</u> Conductivité électrique dans les verres de chalcogènes à travers les effets polaroniques</i>	<i><u>Ghania O.</u> The use of the NDT by micro magnetic methods in determination of structure</i>

**Coffee Break**

**Plenary B-3, Room A, Chair: E. Ruiz-Hitzky**

16:10-16:30 *Fontana M. Doped ILiNbO3 as a versatile material for optical applications*  
 16:30-16:50 *Chahboun A. Photoluminescence from InAs/GaAs self-assembled quantum dots*  
 16:50-17:10 *El H. Abdelillah. Charge storage and coulomb blockade in germanium nanocrystals*

**Poster Presentation D-3 (2-3 min. for presentation), Room A Chair: Y. Gagou**

Presentations: 4D205, 4D206, 4D207, 4D208, 5D215, 5D216, 6D239, 6D240, 6D241, 6D242, 6D243

**Posters (Multifunctional materials) 4Dxxx, 5Dxxx, 6Dxxx, 4Pxxx, 5Pxxx, 6Pxxx,**

**18:45-19:00 - Closing**